

## HX40106-S Six-way Schmidt trigger

### General situation

HX40106-S is composed of six CMOS reverse circuits, each circuit input has a Schmitt trigger circuit, trigger switch at different potentials, output for positive and negative signals, the voltage difference between the positive voltage (VP) and the negative voltage (VN) is defined as the hysteresis voltage (VH).

When in use, the input end of the unused channel needs to be connected to the power supply or ground to reduce the power consumption of the chip.

### Main feature

Schmitt trigger input  
Standardized symmetrical output characteristics  
Power supply voltage: 3 ~ 16V  
Input voltage: 0 ~ VDD  
5V、10V、15V Parameter rating  
Low static current:  $I_{DD} < 1 \mu A$   
Operating temperature:  $-20^{\circ}C \sim 85^{\circ}C$

### Application field

Waveform and pulse shaping  
Stable multivibrator  
Monostable oscillator  
High noise environment system

### Internal block diagram

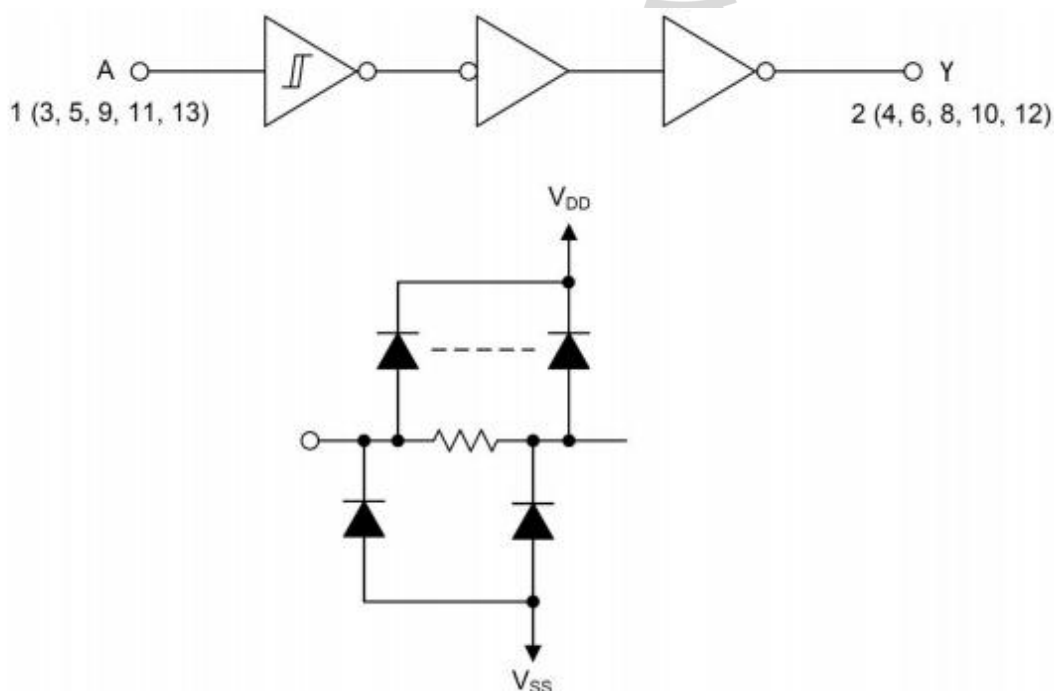
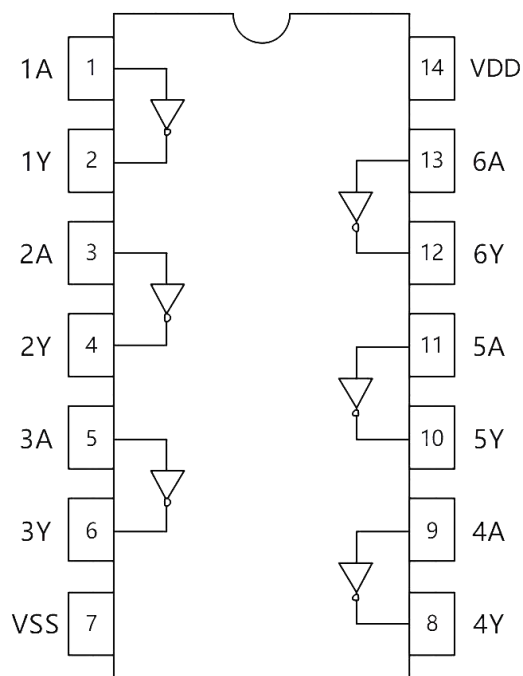


Figure 1. Logic diagram (one buffer) & simple block diagram

## Pin specification



Serial number	Pin definition	Serial number	Pin definition
1	1 Channel input	14	Power source
2	1 Channel output	13	6 Channel input
3	2 Channel input	12	6 Channel output
4	2 Channel output	11	5 Channel input
5	3 Channel input	10	5 Channel output
6	3 Channel output	9	4 Channel input
7	Ground	8	4 Channel output

## Limiting maximum parameter

Argument	Symbol	Min	Max
Supply voltage	VDD	-0.5V	16V
Input voltage	VIN	-0.5V	VDD+0.5V
Input current	IIN	-10mA	+10mA
Storage temperature	Tstg	-65°C	150°C
Junction temperature	TJ	-	150°C
Welding temperature	-	-	265°C
Electrostatic discharge	ESD (HBM)	-	2000V

Note: Exceeding the above limit value may cause permanent damage to the chip.

## Recommended working conditions

Argument	Symbol	Min	Max
Operating voltage	VDD	3V	15V
Input voltage	VIN	0V	VDD
Operating temperature	TA	-20°C	85°C

## Input/output truth table

Input (n A)	Exportation (n Y)
L	H
H	L

Note: L= low-level voltage; H= high level voltage.

## Electrical characteristics – Static parameters

(No special instructions, TA=25°C)

Symbol	Argument	Test condition		Min	Typ	Max	Unit
VOL	Output low level voltage	VIN = 5V	VDD = 5V	-	0	0.05	V
		VIN = 10V	VDD = 10V	-	0	0.05	
		VIN = 15V	VDD = 15V	-	0	0.05	
VOH	Output high level voltage	VIN = 0V	VDD = 5V	4.95	5	-	V
		VIN = 0V	VDD = 10V	9.95	10	-	
		VIN = 0V	VDD = 15V	14.95	15	-	
VP	Positive trigger threshold voltage	-	VDD = 5V	2.9	3.6	4.3	V
		-	VDD = 10V	5.5	6.9	8.2	
		-	VDD = 15V	8.5	10.5	12.5	
VN	Negative trigger threshold voltage	-	VDD = 5V	0.7	1.7	2.7	V
		-	VDD = 10V	2.0	3.4	4.8	
		-	VDD = 15V	3.4	5.2	7.2	

V <sub>H</sub>	Hysteresis voltage	-	V <sub>DD</sub> = 5V	0.9	1.9	2.8	V
		-	V <sub>DD</sub> = 10V	1.8	3.5	4.0	
		-	V <sub>DD</sub> = 15V	3.2	5.3	7.2	
I <sub>IL</sub>	Output low level perfusion current	V <sub>O</sub> = 0.4V	V <sub>DD</sub> = 5V	0.5	1.6	-	mA
		V <sub>O</sub> = 0.5V	V <sub>DD</sub> = 10V	2.5	5	-	
		V <sub>O</sub> = 1.5V	V <sub>DD</sub> = 15V	3.5	16	-	
I <sub>OH</sub>	Output high level source current	V <sub>O</sub> = 4.6V	V <sub>DD</sub> = 5V	-	-1	-0.5	mA
		V <sub>O</sub> = 9.5V	V <sub>DD</sub> = 10V	-	-2.6	-1.3	
		V <sub>O</sub> = 13.5V	V <sub>DD</sub> = 15V	-	-7.2	-3.5	
I <sub>IN</sub>	Input current	V <sub>IN</sub> =0V~15V	V <sub>DD</sub> =15V	-1	-	1	uA
I <sub>DD</sub>	Supply current	V <sub>IN</sub> =0V or 5V	V <sub>DD</sub> = 5V	-	-	1	uA
		V <sub>IN</sub> =0V or 10V	V <sub>DD</sub> = 10V	-	-	1	
		V <sub>IN</sub> =0V or 15V	V <sub>DD</sub> = 15V	-	-	1	

Note: The conversion characteristic waveform is as follows

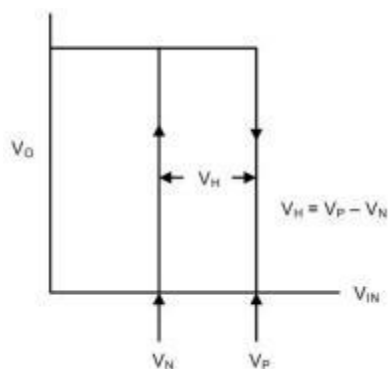


Figure 2. Transformation characteristics

## Electrical characteristics – Time parameters

Argument	Test condition	Min	Typ	Max	Unit	
$t_{PHL}$	$C_L = 50\text{pF}$ $R_L = 200\text{K}\ \Omega$ $V_{IN} = 1\text{KHz}, D = 50\%\text{Square wave}$	$V_{DD}=5\text{V}$	-	35	110	ns
		$V_{DD}=10\text{V}$	-	22	60	ns
		$V_{DD}=15\text{V}$	-	32	50	ns
$t_{PLH}$	$t_r=t_f \leq 20\text{ns}$	$V_{DD}=5\text{V}$	-	46	110	ns
		$V_{DD}=10\text{V}$	-	30	60	ns
		$V_{DD}=15\text{V}$	-	20	50	ns
$t_{THL}$	$C_L = 50\text{pF}$ $R_L = 200\text{K}\ \Omega$ $V_{IN} = 1\text{KHz}, D = 50\%\text{Square wave}$	$V_{DD}=5\text{V}$	-	52	200	ns
		$V_{DD}=10\text{V}$	-	26	100	ns
		$V_{DD}=15\text{V}$	-	54	80	ns
$t_{TLH}$	$t_r=t_f \leq 20\text{ns}$	$V_{DD}=5\text{V}$	-	75	200	ns
		$V_{DD}=10\text{V}$	-	40	100	ns
		$V_{DD}=15\text{V}$	-	36	80	ns
$C_{IN}$	Any Input	-	-	15	pF	

Note: The time parameter test circuit is as follows

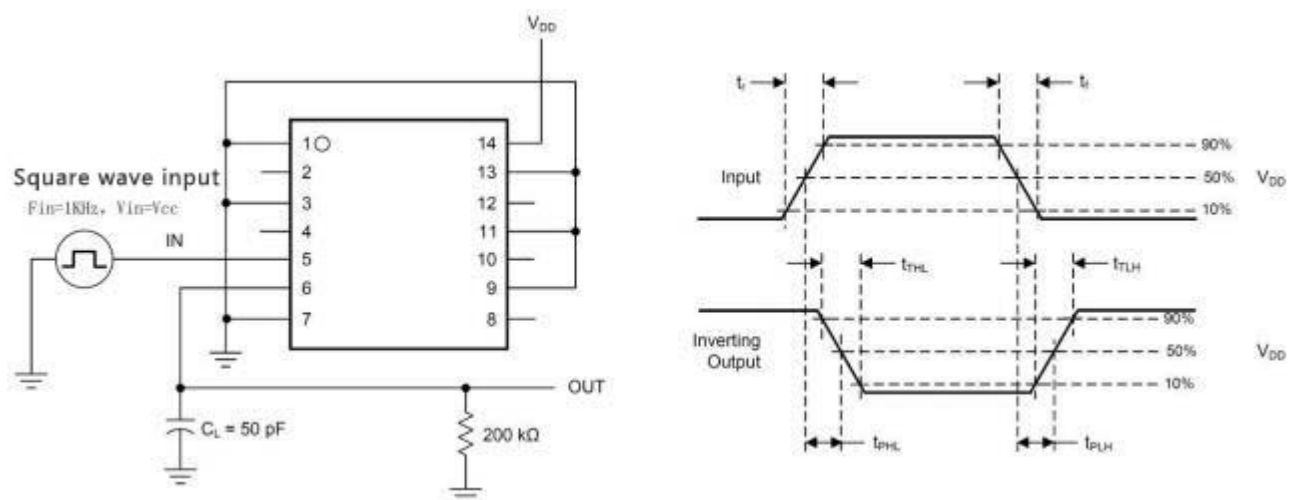


Figure 3. Schematic diagram of time test & output waveform

## Typical application (1) Waveform shaper

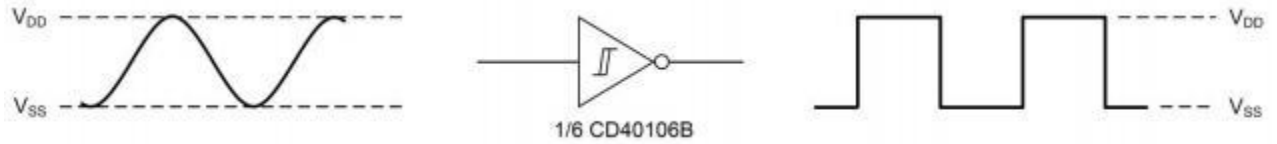


Figure 4. Waveform shaper

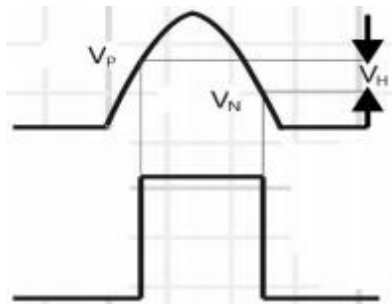


Figure 5. Shaping waveform

In the above app, note:

- 1) Input waveform voltage amplitude should not be too large, should be lower than VDD voltage;
- 2) The output load also needs to be limited to avoid exceeding the maximum power of the chip.

## (2) Monostable multivibrator

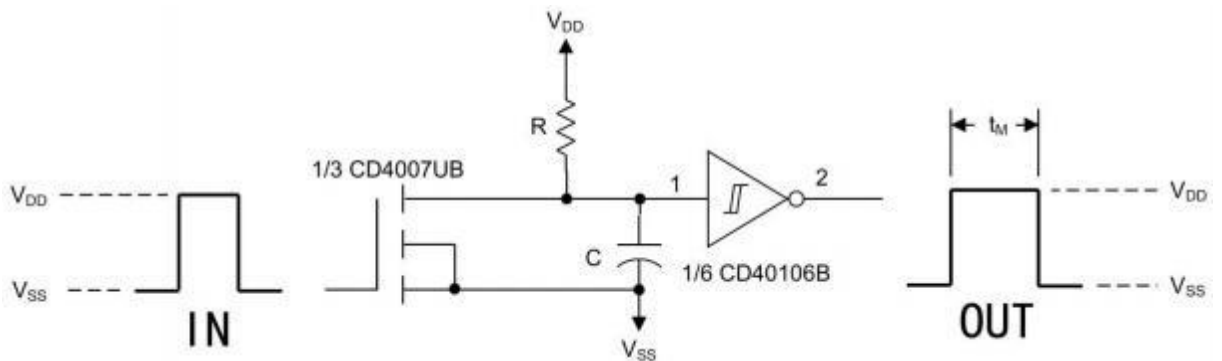


Figure 6. Monostable multivibrator

## (3) Unsteady multivibrator

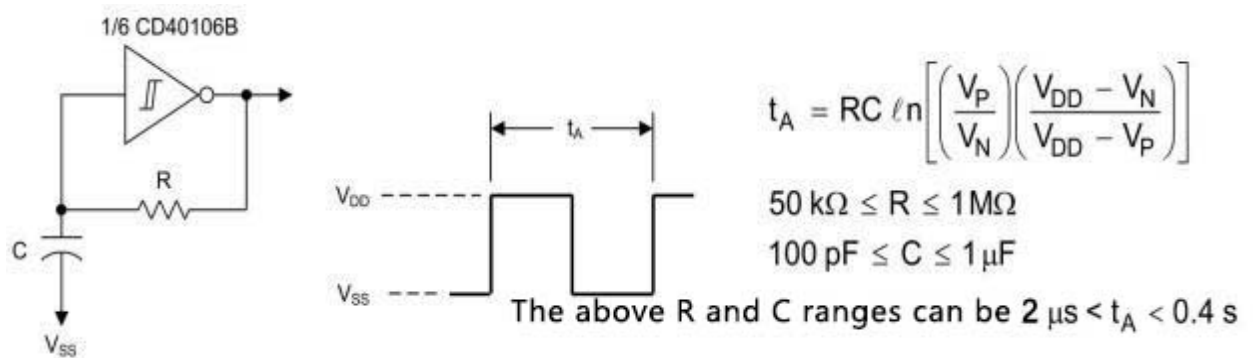
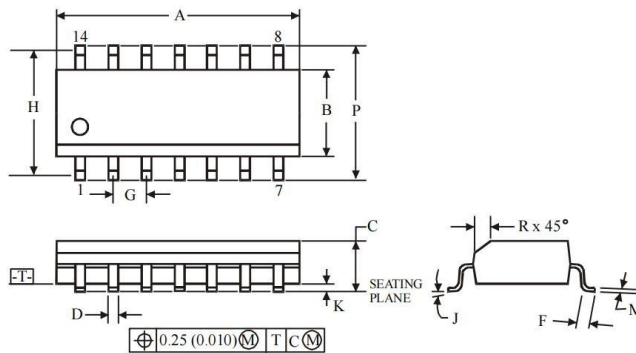


Figure 7. Unsteady multivibrator

## Encapsulation

### SOP14 (Package Outline Dimensions)

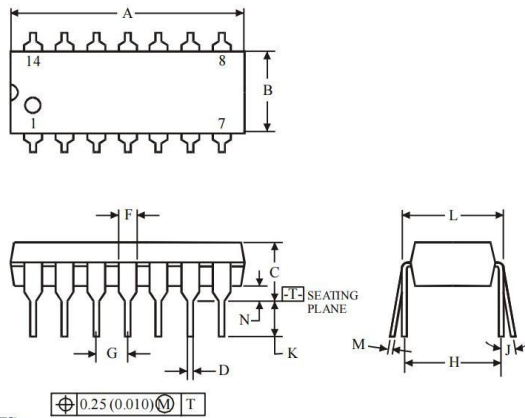


Symbol	Dimension, mm	
	MIN	MAX
A	8.55	8.75
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.27	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5

**NOTES:**

1. Dimensions A and B do not include mold flash or protrusion.
2. Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B - 0.25 mm (0.010) per side.

### DIP14 (Package Outline Dimensions)



Symbol	Dimension, mm	
	MIN	MAX
A	18.67	19.69
B	6.1	7.11
C	5.33	
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

**NOTES:**

1. Dimensions "A", "B" do not include mold flash or protrusions.  
Maximum mold flash or protrusions 0.25 mm (0.010) per side.

Part Number	Package Type	Package	quantity
HX40106-S	SOP-14	Taping	2500